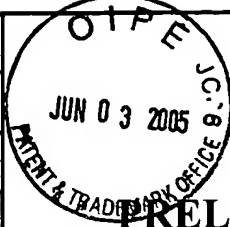


First Named Inventor	Leonard Forbes	 PRELIMINARY AMENDMENT
Serial No.	10/808,059	
Filing Date	March 24, 2004	
Group Art Unit	2814	
Examiner Name	M. Pizarro Crespo	
Confirmation No.	4221	
Attorney Docket No.	400.285US01	
Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC FORMED BY THE LOW TEMPERATURE OXIDIZATION OF METALS		

Commissioner for Patents
M.S. Amendment
P.O. Box 1450
Alexandria, VA 22313-1450

Prior to initial review, please amend the above-identified application as follows to correct a typographical error in the application filing:

PRELIMINARY AMENDMENT

PAGE 3

Serial No. 10/808;059

Attorney Docket No. 400.285US01

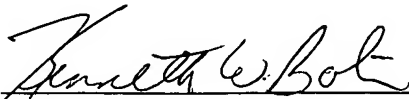
Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC FORMED BY THE
LOW TEMPERATURE OXIDIZATION OF METALS

If the Examiner has any questions or concerns regarding this application, please contact the undersigned at (612) 312-2211. No new matter has been added and Applicant believes no additional fee is required by this Preliminary Amendment.

Respectfully submitted,

Date: _____

5/31/05



Kenneth W. Bolvin
Reg. No. 34,125

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